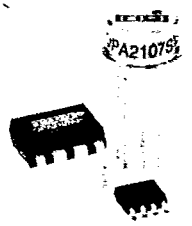
T-79-15

BURR-BROWN®



OPA2107

Precision Dual *Difet* ® OPERATIONAL AMPLIFIER

FEATURES

- VERY LOW NOISE: 8nV/√Hz at 10kHz
- LOW V_{OS}: 500µV max
- LOW DRIFT: 5µV/°C max
- LOW I_B: 5pA max
- FAST SETTLING TIME: 2µs to 0.01%
- UNITY-GAIN STABLE

APPLICATIONS

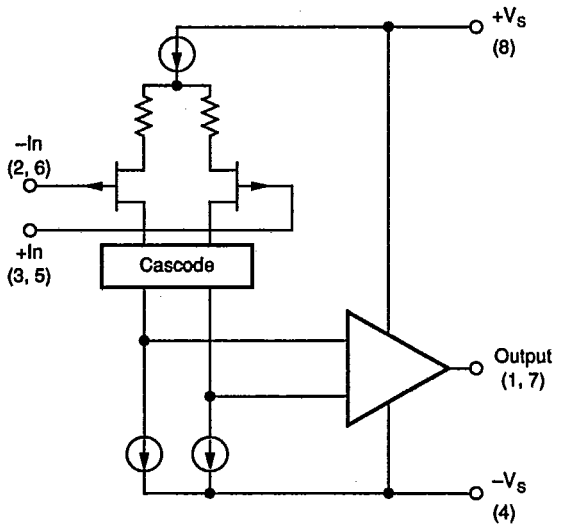
- DATA ACQUISITION
- DAC OUTPUT AMPLIFIER
- OPTOELECTRONICS
- HIGH-IMPEDANCE SENSOR AMPS
- HIGH-PERFORMANCE AUDIO CIRCUITRY
- MEDICAL EQUIPMENT, CT SCANNERS

DESCRIPTION

The OPA2107 dual operational amplifier provides precision ***Difet*** performance with the cost and space savings of a dual op amp. It is useful in a wide range of precision and low-noise analog circuitry and can be used to upgrade the performance of designs currently using BIFET® type amplifiers.

The OPA2107 is fabricated on a proprietary dielectrically isolated (***Difet***) process. This holds input bias currents to very low levels without sacrificing other important parameters, such as input offset voltage, drift and noise. Laser-trimmed input circuitry yields excellent DC performance. Superior dynamic performance is achieved, yet quiescent current is held to under 2.5mA per amplifier. The OPA2107 is unity-gain stable.

The OPA2107 is available in plastic DIP, metal TO-99, and SOIC packages. Industrial and Military temperature range versions are available.



Difet® Burr-Brown Corp.
BIFET® National Semiconductor

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SPECIFICATIONS

T_A = +25°C, V_S = ±15V unless otherwise noted.

PARAMETER	CONDITION	OPA2107AM, SM, AP, AU			OPA2107BM			UNITS
		MIN	TYP	MAX	MIN	TYP	MAX	
OFFSET VOLTAGE[1]								
Input Offset Voltage	V_{CM} = 0V		100	1mV		50	500	µV
Over Specified Temperature			0.5	2		0.2	1	mV
SM Grade			0.8	2.5				mV
Average Drift Over Specified Temperature			3	10		2	5	µV/°C
Power Supply Rejection	V_S = ±10 to ±18V	80	96		84	100		dB
INPUT BIAS CURRENT[1]								
Input Bias Current	V_{CM} = 0V		4	10		2	5	pA
Over Specified Temperature			0.25	1.5		0.15	1	nA
SM Grade			4	35				nA
Input Offset Current	V_{CM} = 0V		1	8		0.5	3	pA
Over Specified Temperature				1			0.5	nA
SM Grade			1	28				nA
INPUT NOISE								
Voltage: f = 10Hz	R_S = 0		30			*		nV/√Hz
f = 100Hz			12			*		nV/√Hz
f = 1kHz			9			*		nV/√Hz
f = 10kHz			8			*		nV/√Hz
BW = 0.1 to 10Hz			1.2			*		µVp-p
BW = 10 to 10kHz			0.85			*		µVrms
Current: f = 0.1Hz thru 20kHz			1.2			0.9		fA/√Hz
BW = 0.1Hz to 10Hz			23			17		fAp-p
INPUT IMPEDANCE								
Differential			10^{13} || 2			*		Ω || pF
Common-Mode			10^{14} || 4			*		Ω || pF
INPUT VOLTAGE RANGE								
Common-Mode Input Range		±10.5	±11		*	*		V
Over Specified Temperature		±10.2	±10.5		*	*		V
SM Grade		±10	±10.3					V
Common-Mode Rejection	V_{CM} = ±10V	80	94		84	100		dB
OPEN-LOOP GAIN								
Open-Loop Voltage Gain	V_O = ±10V, R_L = 2kΩ	82	96		84	100		dB
Over Specified Temperature		80	94		82	96		dB
SM Grade		80	92					dB
DYNAMIC RESPONSE								
Slew Rate	G = +1	13	18		*	*		V/µs
Settling Time: 0.1%	G = –1, 10V Step		1.5			*		µs
0.01%			2			*		µs
Gain-Bandwidth Product	G = 100		4.5			*		MHz
THD + Noise	G = +1, f = 1kHz		0.001			*		%
Channel Separation	f = 100Hz, R_L = 2kΩ		120			*		dB
POWER SUPPLY								
Specified Operating Voltage			±15			*		V
Operating Voltage Range		±4.5		±18	*		*	V
Current			±4.5	±5		*	*	mA
OUTPUT								
Voltage Output	R_L = 2kΩ	±11	±12		*	*		V
Over Specified Temperature		±10.5	±11.5		*	*		V
SM Grade		±10.2	±11.3					V
Short Circuit Current		±10	±40		*	*		mA
Output Resistance, Open-Loop	1MHz		70			*		Ω
Capacitive Load Stability	G = +1		1000			*		pF
TEMPERATURE RANGE								
Specification								
AP, AU, AM, BM		–25		+85	*		*	°C
SM		–55		+125				°C
Operating								
AP, AU		–25		+85				°C
AM, BM, SM		–55		+125	*		*	°C
Storage								
AP, AU		–40		+125				°C
AM, BM, SM		–65		+150	*		*	°C
Thermal Resistance (θ_{J-A})								
AP			90					°C/W
AU			175					°C/W
AM, BM, SM			200			*		°C/W

* Specifications same as OPA2107AM.

NOTE: (1) Specified with devices fully warmed up.

ORDERING INFORMATION

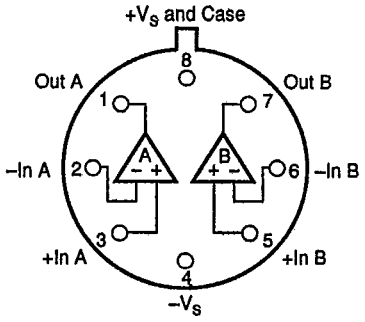
MODELS	PACKAGE	SPECIFICATION TEMPERATURE RANGE	USA OEM PRICES 1-24	25-99	100+
OPA2107AP	Plastic DIP	–25 to +85°C	$10.80	$7.50	$5.70
OPA2107AM	Metal TO-99	–25 to +85°C	13.45	10.20	8.05
OPA2107BM	Metal TO-99	–25 to +85°C	19.20	13.95	10.90
OPA2107SM	Metal TO-99	–55 to +125°C	34.65	25.95	19.80
OPA2107AU	SO-8 SOIC	–25 to +85°C	12.40	8.65	6.55

ABSOLUTE MAXIMUM RATINGS

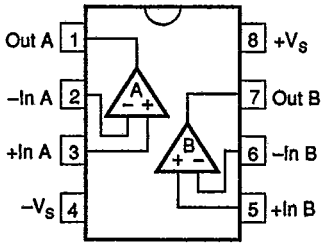
Supply Voltage ..... ±18V
Input Voltage Range ..... $\pm V_S$ ±2V
Differential Input Voltage ..... Total V_S ±4V
Operating Temperature
M Package ..... –55°C to +125°C
P and U Packages ..... –25°C to + 85°C
Storage Temperature
M Package ..... –65°C to +150°C
P and U Packages ..... –40°C to +125°C
Output Short Circuit to Ground (T_A = +25°C) ..... Continuous
Junction Temperature ..... +175°C
Lead Temperature
M and P Packages (soldering, 10s) ..... +300°C
U Package, SOIC (3s) ..... +260°C

PIN CONFIGURATIONS

Top View – M Package

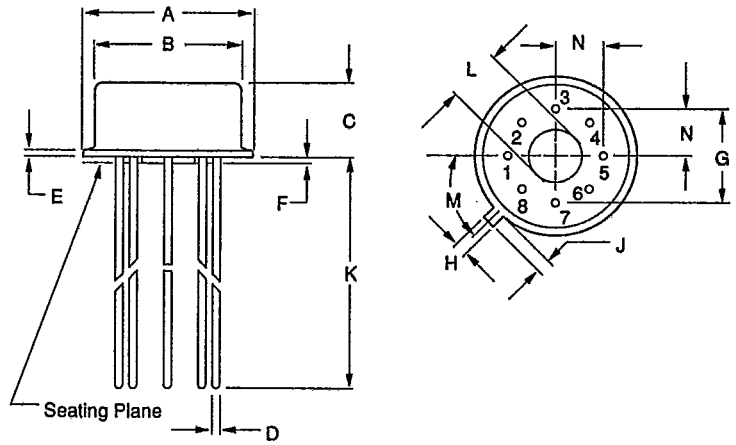


Top View – P & U Packages



MECHANICAL

M Package — Metal TO-99

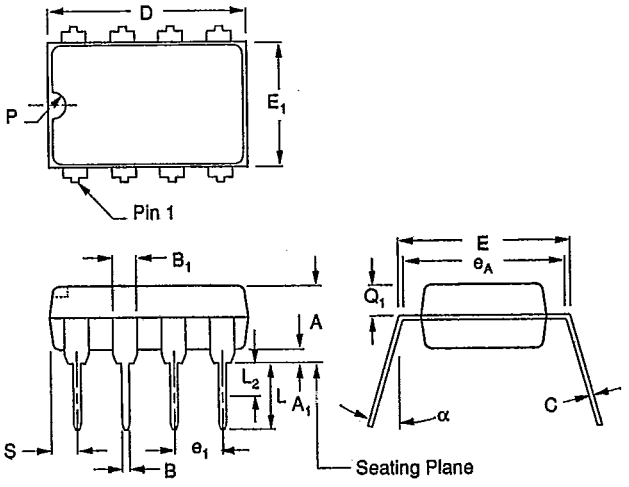


DIM	INCHES MIN	INCHES MAX	MILLIMETERS MIN	MILLIMETERS MAX
A	.335	.370	8.51	9.40
B	.305	.335	7.75	8.51
C	.165	.185	4.19	4.70
D	.016	.021	0.41	0.53
E	.010	.040	0.25	1.02
F	.010	.040	0.25	1.02
G	.200 BASIC		5.08 BASIC	
H	.028	.034	0.71	0.86
J	.029	.045	0.74	1.14
K	.500	—	12.7	—
L	.110	.160	2.79	4.06
M	45° BASIC		45° BASIC	
N	.095	.105	2.41	2.67

NOTE: Leads in true position within 0.01" (0.25mm) R at MMC at seating plane. Pin numbers shown for reference only. Numbers may not be marked on package.

MECHANICAL (CONT)

P Package — 8-Pin Plastic DIP

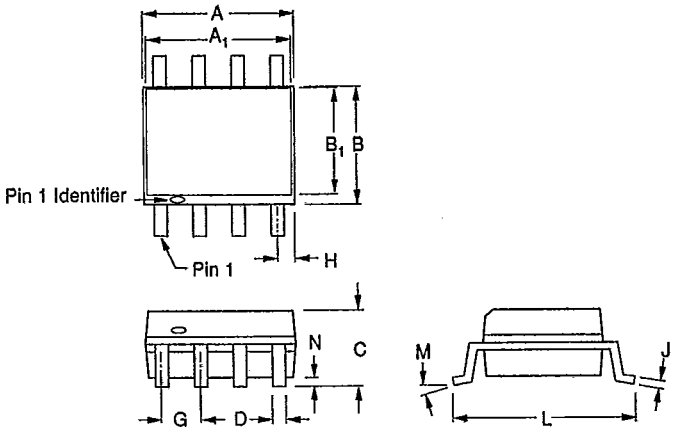


DIM	INCHES MIN	INCHES MAX	MILLIMETERS MIN	MILLIMETERS MAX
A	.155	.200	3.94	5.08
A1	.020	.050	0.51	1.27
B	.014	.020	0.36	0.51
B1	.045	.065	1.14	1.65
C	.008	.012	0.20	0.30
D(1)	.370	.400	9.40	10.16
E	.300	.325	7.62	8.26
E1	.240	.260	6.10	6.60
e1	.100 BASIC		2.54 BASIC	
eA	.300 BASIC		7.62 BASIC	
L	.125	.150	3.18	3.81

DIM	INCHES MIN	INCHES MAX	MILLIMETERS MIN	MILLIMETERS MAX
L2(2)	0	.030	0.00	0.76
α	0°	15°	0°	15°
P	.015	.050	0.38	1.270
Q1	.040	.075	1.02	1.91
S(1)	.015	.050	0.38	1.27

(1) Not JEDEC Std.
(2) e1 and e_A apply in zone L_2 when unit installed.
NOTE: Leads in true position within 0.01" (0.25mm) R at MMC at seating plane.

U Package — 8-Pin SOIC



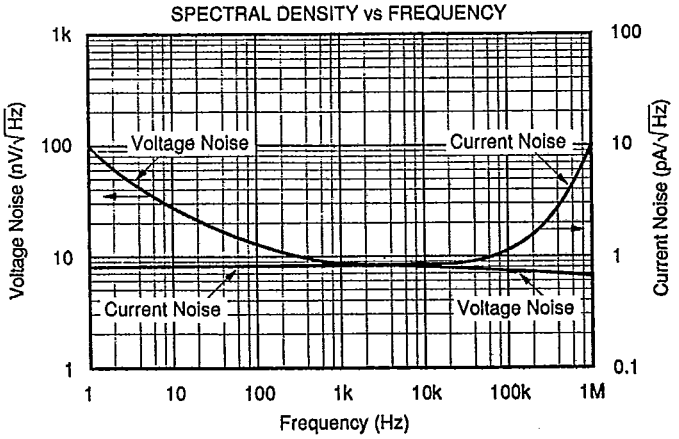
DIM	INCHES MIN	INCHES MAX	MILLIMETERS MIN	MILLIMETERS MAX
A	.185	.201	4.70	5.11
A1	.178	.201	4.52	5.11
B	.146	.162	3.71	4.11
B1	.130	.149	3.30	3.78
C	.054	.145	1.37	3.69
D	.015	.019	0.38	0.48
G	.050 BASIC		1.27 BASIC	
H	.018	.026	0.46	0.66
J	.008	.012	0.20	0.30
L	.220	.252	5.59	6.40
M	0°	10°	0°	10°
N	.000	.012	0.00	0.30

NOTE: Leads in true position within 0.01" (0.25mm) R at MMC at seating plane.

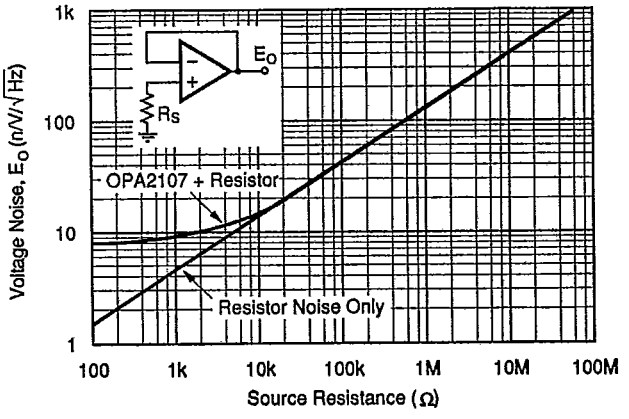
TYPICAL PERFORMANCE CURVES

T_A = +25°C. V_S = ±15V unless otherwise noted.

INPUT VOLTAGE AND CURRENT NOISE SPECTRAL DENSITY vs FREQUENCY



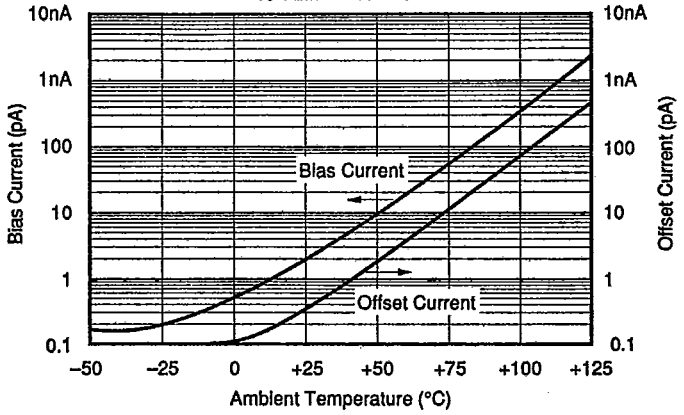
TOTAL INPUT VOLTAGE NOISE SPECTRAL DENSITY at 1kHz vs SOURCE RESISTANCE



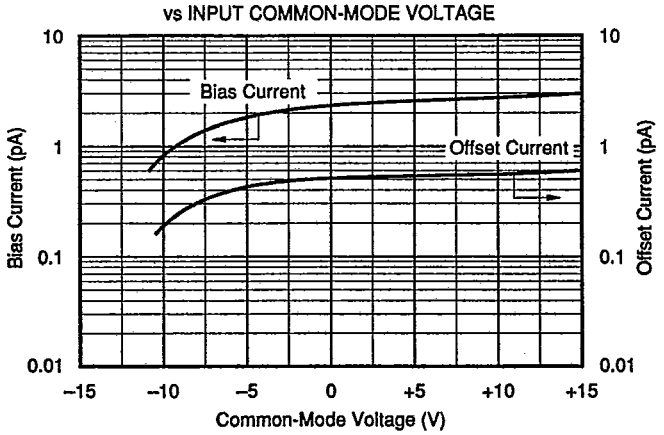
TYPICAL PERFORMANCE CURVES (CONT)

T_A = +25°C, V_S = ±15V unless otherwise noted.

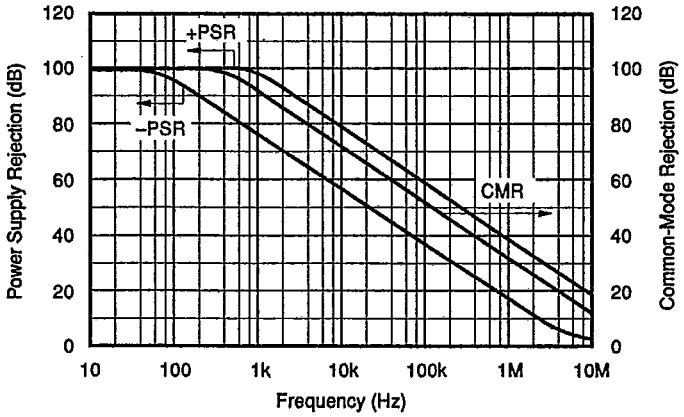
BIAS AND OFFSET CURRENT vs TEMPERATURE



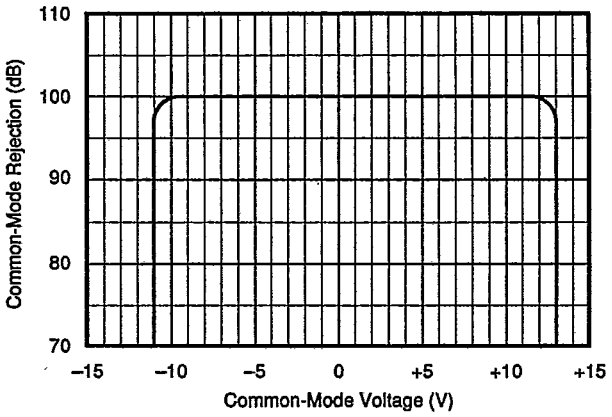
BIAS AND OFFSET CURRENT vs INPUT COMMON-MODE VOLTAGE



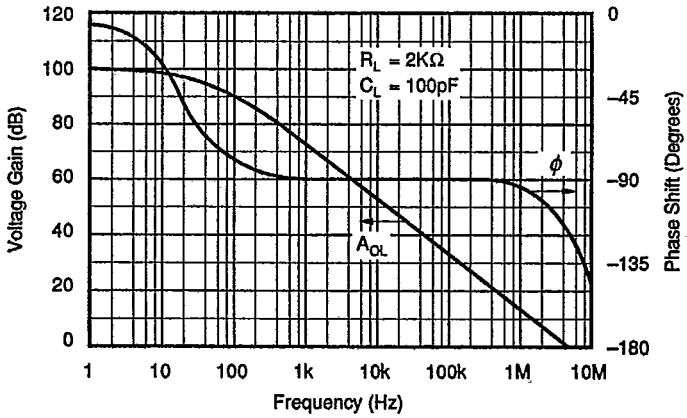
POWER SUPPLY AND COMMON-MODE REJECTION vs FREQUENCY



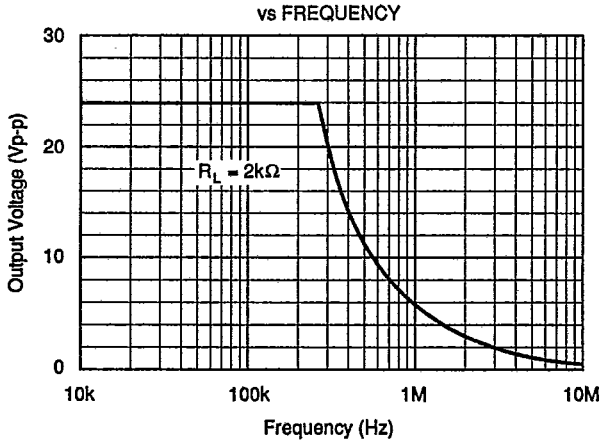
COMMON-MODE REJECTION vs INPUT COMMON-MODE VOLTAGE



OPEN-LOOP FREQUENCY RESPONSE



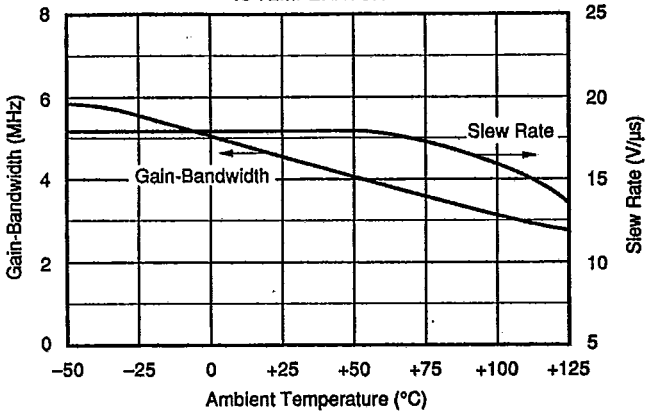
MAXIMUM OUTPUT VOLTAGE SWING vs FREQUENCY



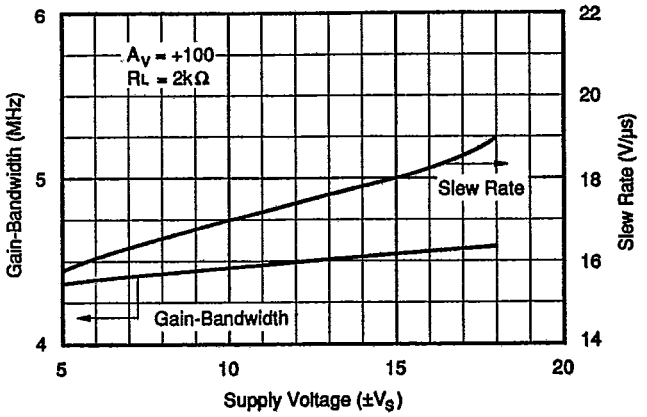
TYPICAL PERFORMANCE CURVES (CONT)

T_A = +25°C, V_S = ±15V unless otherwise noted.

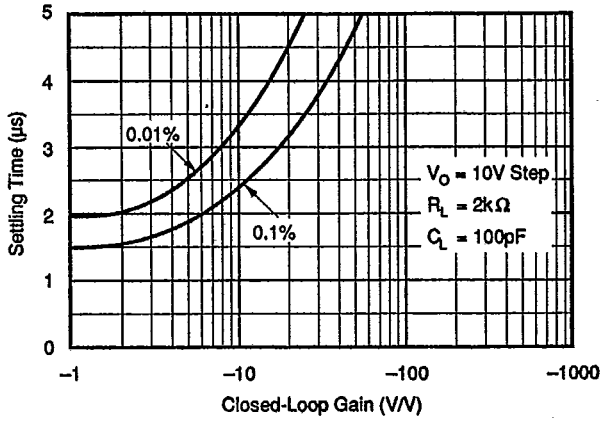
GAIN-BANDWIDTH AND SLEW RATE vs TEMPERATURE



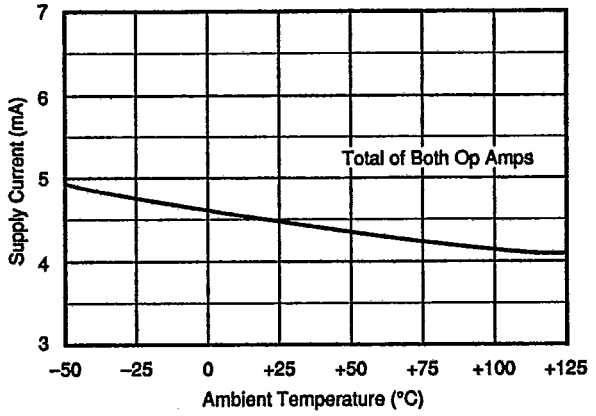
GAIN-BANDWIDTH AND SLEW RATE vs SUPPLY VOLTAGE



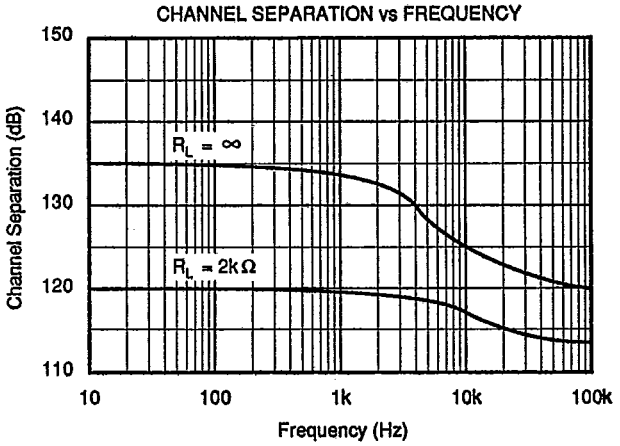
SETTLING TIME vs CLOSED-LOOP GAIN



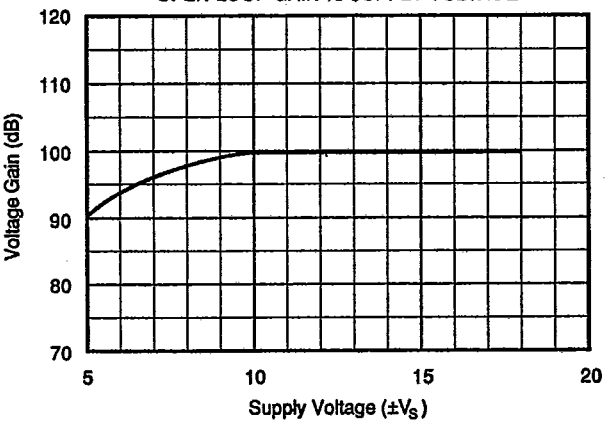
SUPPLY CURRENT vs TEMPERATURE



CHANNEL SEPARATION vs FREQUENCY



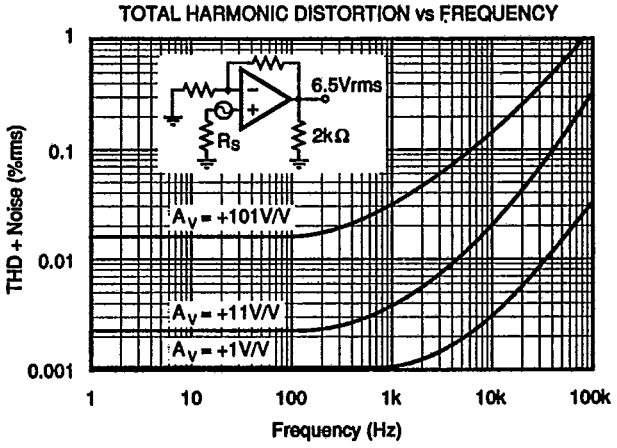
OPEN-LOOP GAIN vs SUPPLY VOLTAGE



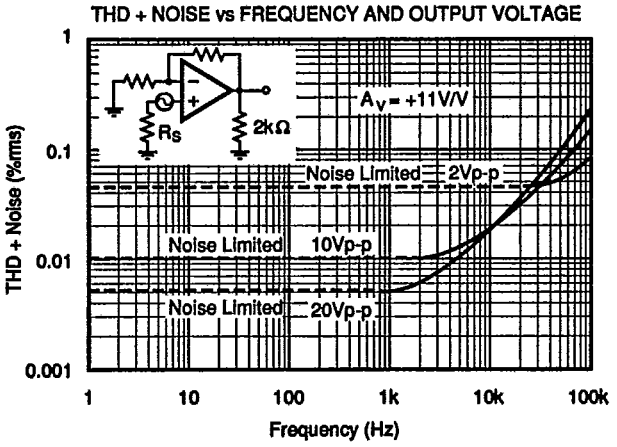
TYPICAL PERFORMANCE CURVES (CONT)

T_A = +25°C, V_S = ±15V unless otherwise noted.

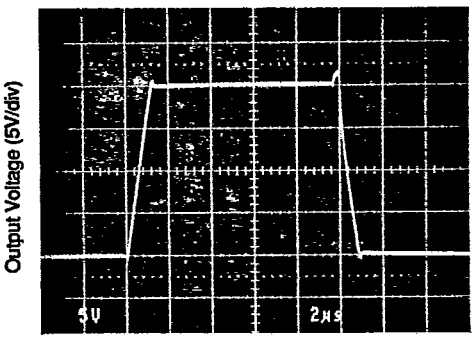
TOTAL HARMONIC DISTORTION vs FREQUENCY



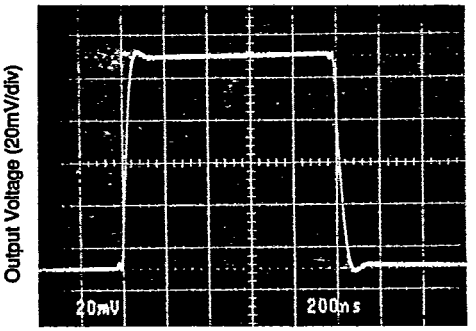
THD + NOISE vs FREQUENCY AND OUTPUT VOLTAGE



OPA2107 LARGE-SIGNAL RESPONSE



OPA2107 SMALL-SIGNAL RESPONSE



APPLICATIONS INFORMATION AND CIRCUITS

The OPA2107 is unity-gain stable and has excellent phase margin. This makes it easy to use in a wide variety of applications.

Power supply connections should be bypassed with capacitors positioned close to the amplifier pins. In most cases, 0.1µF ceramic capacitors are adequate. Applications with larger load currents and fast transient signals may need up to 1µF tantalum bypass capacitors.

INPUT BIAS CURRENT

The OPA2107's ***Difet*** input stages have very low input bias current—an order of magnitude lower than BIFET op amps. Circuit board leakage paths can significantly degrade performance. This is especially evident with the SO-8 surface-mount package where pin-to-pin dimensions are particularly small. Residual soldering flux, dirt, and oils, which conduct leakage current, can be removed by proper cleaning. In most instances a two-step cleaning process is adequate using a clean organic solvent rinse followed by de-ionized water. Each rinse should be followed by a 30-minute bake at 85°C.

A circuit board guard pattern effectively reduces errors due to circuit board leakage (Figure 1). By encircling critical high impedance nodes with a low impedance connection at the same circuit potential, any leakage currents will flow harmlessly to the low impedance node. Guard traces should be placed on all levels of a multiple-layer circuit board.

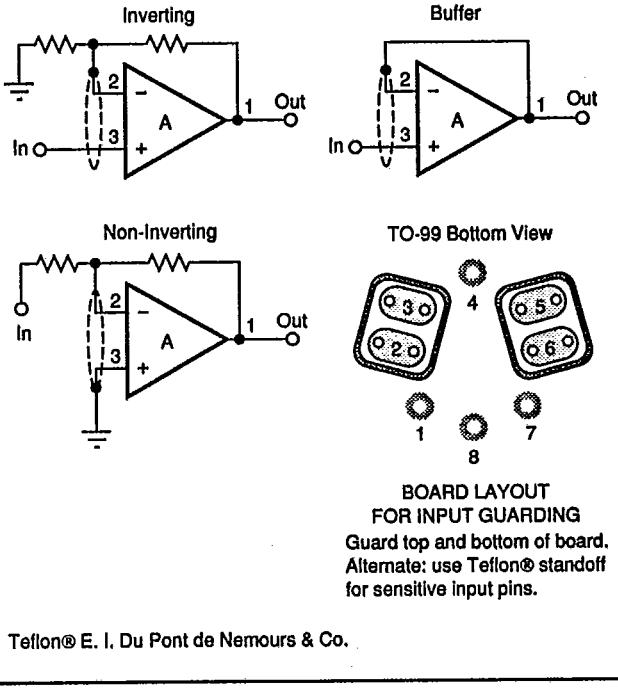


FIGURE 1. Connection of Input Guard.

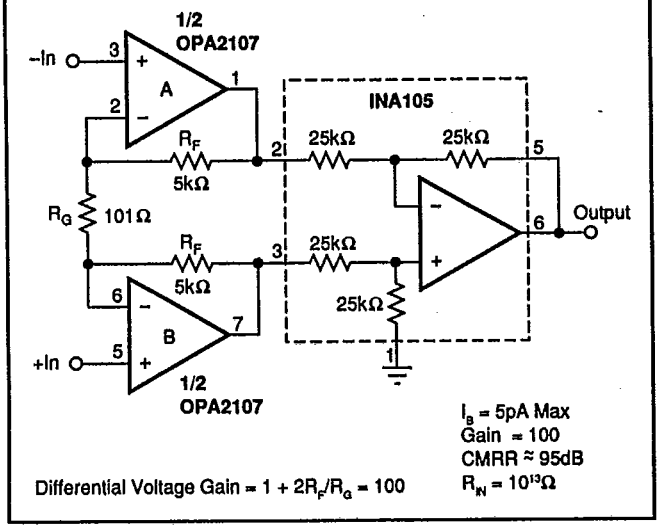


FIGURE 2. FET Input Instrumentation Amplifier.

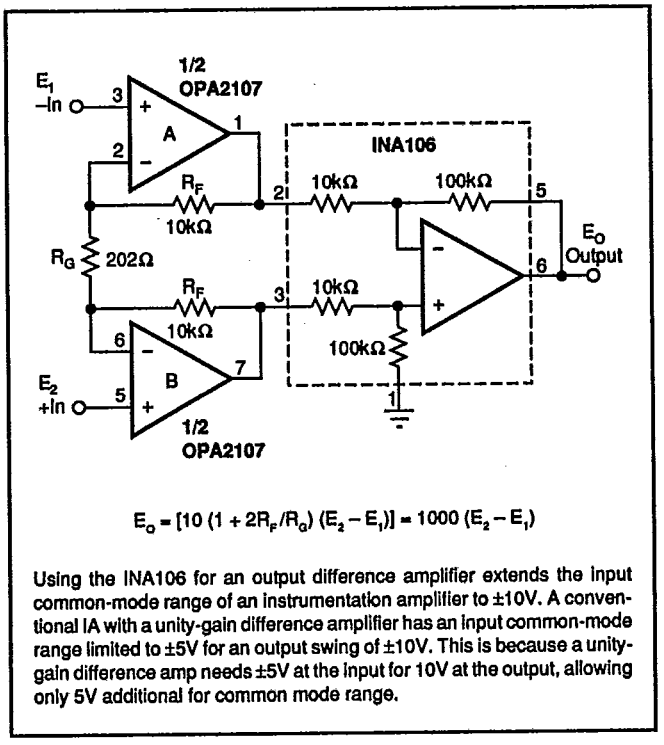


FIGURE 3. Precision Instrumentation Amplifier.